

Influence of thermally induced oxygen order on mobile ion dynamics in $\text{Gd}_2(\text{Ti}_{0.65}\text{Zr}_{0.35})_2\text{O}_7$

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We report on the influence of oxygen order in the oxygen-ion dynamics in the ionic conductor $\text{Gd}_2(\text{Ti}_{0.65}\text{Zr}_{0.35})_2\text{O}_7$. The metastable $\text{Gd}_2(\text{Ti}_{0.65}\text{Zr}_{0.35})_2\text{O}_7$ powders prepared by mechanical milling present an anion-deficient fluorite type of structure, stable up to about 800 °C. Thermal treatments at higher temperatures facilitate the gradual rearrangement of the cation and anion substructures and the relaxation of mechanochemically induced defects. Interestingly, metastable pyrochlores showing a very unusual cation distribution were observed during the thermally induced defect-recovery process. We have found that the ionic conductivity due to mobile oxygen ions increases significantly with increasing sintering temperature from 800 to 1500 °C as a result of a systematic decrease in the activation energy for the dc conductivity from 1.23 to 0.78 eV. Electrical conductivity relaxation is well described by stretched exponentials of the form $\Phi(t) = \exp[-(t/\tau)^{1-n}]$, and the fractional exponent n decreases systematically from $n=0.51$ to 0.18 with increasing sintering temperature. These results are explained in terms of weaker ion-ion interactions in the increasingly ordered structure of the samples sintered at higher temperatures, and point to the importance of structural disorder in determining the dynamics of mobile oxygen ions.

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I. INTRODUCTION

In oxide-ion conductors, oxygen transport takes place by hopping to adjacent oxygen vacancies in the structure. Thus, long-range motion of oxygen ions is found to be thermally activated and results in a dc conductivity of the form $\sigma_{dc} = (\sigma_{\infty}/T)\exp(-E_{dc}/kT)$, with high activation energies E_{dc} , typically of the order of 1 eV. *A priori*, the activation energy should be determined by the energy barrier that oxygen ions must overcome to hop to neighboring vacant sites, but other factors may also affect ion dynamics and consequently the values found for E_{dc} .¹⁻³ Here, we investigate the influence of structural order in oxygen hopping dynamics and their importance in determining the effective activation energy of long-range oxygen diffusion in oxide-ion conductors.

Among oxide-ion conductors, those of pyrochlore structure have been shown to be promising candidates to substitute materials currently used in fuel cells.^{4,5} Pyrochlore oxides $A_2B_2O_7$ are a very large family of compounds showing a great variety of physical and chemical properties as a function of chemical composition and the existing atomic ordering (disordering) and oxygen vacancies. Thus, while some pyrochlores such as $\text{Gd}_2\text{Zr}_2\text{O}_7$ are electronically insulating and fast high-temperature ionic conductors, others such as $\text{Gd}_2\text{Mo}_2\text{O}_7$ display at room temperature a metallic conducting behavior.^{6,7} The fully ordered or “ideal” pyrochlore oxide $A_2B_2O(1)_6O(2)$ presents a cubic symmetry [symmetry group (SG): $Fd\bar{3}m$] and can be described in terms of a superstructure of the ideal anion-deficient fluorite structure (cubic, SG: $Fm\bar{3}m$) with twice the cell constant, $a \approx 10 \text{ \AA}$.⁷ From the two available sites, the larger cation is normally found at the eight-coordinated A site ($16c$) located at the center of a

scalenohedron, whereas the smaller cation occupies the six-coordinated B site ($16d$) at the center of a trigonal antiprism. The oxygen $O(1)$ atoms occupy the $48f$ site coordinated by two B and two A cations, whereas the $O(2)$ atoms occupy the $8a$ site, tetrahedrally coordinated by four A cations. There is another anionic tetrahedral site $8b$ [$O(3)$], coordinated by four B ions which is systematically vacant in ordered pyrochlores as opposed to anion-deficient fluorites where vacancies are randomly distributed throughout the anion substructure. However, different degrees of atomic disorder and high oxygen mobility can be obtained in systems of solid solutions by using the appropriate substitutions on the A and B sites.⁸ Thus, the $\text{Gd}_2\text{Ti}_2\text{O}_7$ - $\text{Gd}_2\text{Zr}_2\text{O}_7$ system shows complete miscibility. The cation and anion substructures in the $\text{Gd}_2(\text{Ti}_{1-y}\text{Zr}_y)_2\text{O}_7$ solid solution disorder gradually as the Zr content increases, leading to the appearance of oxygen vacancies at $48f$ sites which are known to be responsible for oxygen hopping and diffusion.^{5,9} Correspondingly, a marked increase in oxygen conductivity is observed in this system when $y \geq 0.3$, which has been related to the onset of the anion disordering.⁹

Mechanical milling allows preparing partially disordered and metastable $\text{RE}_2\text{Ti}_2\text{O}_7$ pyrochlores,¹⁰ obtained otherwise only by chemical substitution, ion irradiation, or pressure-induced compression.^{9,11,12} We have reported in a previous work on the influence of chemically induced disorder (Zr substitution for Ti) in oxygen dynamics, and consequently on the electrical properties, of the $\text{Gd}_2(\text{Ti}_{1-y}\text{Zr}_y)_2\text{O}_7$ series.¹³ In this work, we will present the evolution of the structural disorder in metastable $\text{Gd}_2(\text{Ti}_{0.65}\text{Zr}_{0.35})_2\text{O}_7$ powders prepared by mechanical milling with postmilling thermal treatments. That is, for a fixed composition, disorder induced in the

preparation process is systematically relieved by annealing and the electrical properties analyzed as a function of the structure and/or microstructure. The composition $\text{Gd}_2(\text{Ti}_{0.65}\text{Zr}_{0.35})_2\text{O}_7$ was selected for the study because it lies close to the boundary between the fully ordered ideal and the “defect” pyrochlore stability fields found in the $\text{Gd}_2(\text{Ti}_{1-y}\text{Zr}_y)_2\text{O}_7$ solid solution for equilibrium phases.⁹ These facts make this composition an ideal system for investigating the possible influence of structural disorder on the oxygen hopping dynamics and thus on the long-range ionic transport. We investigate this issue by impedance spectroscopy, an appropriate technique to probe ion hopping dynamics, since the dispersive ac conductivity data allow obtaining information on the oxygen dynamics.¹³

II. EXPERIMENT

The $\text{Gd}_2(\text{Ti}_{0.65}\text{Zr}_{0.35})_2\text{O}_7$ powders were prepared as described elsewhere,¹⁴ by dry milling a stoichiometric mixture of the constituent oxides (high-purity monoclinic ZrO_2 , anatase- TiO_2 , and $\text{C-Gd}_2\text{O}_3$), in a planetary ball mill using zirconia vials and balls. Portions of these powder samples were subjected to postmilling thermal treatments at four selected temperatures (800, 1000, 1200, and 1500 °C; soaking time of 12 h; heating and cooling rate of 2 °C/min) and analyzed as described below. The structural and microstructural features of the as-prepared materials were obtained from precise diffraction data obtained on a Bruker D8 high-resolution x-ray powder diffractometer equipped with a position-sensitive detector (PSD) MBraun PSD-50M, using monochromatic $\text{Cu K}\alpha_1$ radiation ($\lambda=1.5406 \text{ \AA}$) obtained with a germanium primary monochromator. The measured angular range, the step size, and counting times were selected to ensure enough resolution (the step size should be at least 1/10 of the full widths at half maximum) and statistics. The instrumental contribution to line broadening was evaluated using NIST LaB_6 standard reference material (SRM 660a; $\mu=1138 \text{ cm}^{-1}$, linear absorption coefficient for $\text{Cu K}\alpha_1$ radiation). The structural refinements were carried out by the Rietveld method using the FULLPROF program¹⁵ and taking into account, simultaneously, the effects of the sample microstructure on the diffraction patterns according to a phenomenological approach described in detail elsewhere.^{10,16}

Electrical conductivity relaxation measurements were carried out by impedance spectroscopy, with a Solartron 1260 frequency response analyzer, on cylindrical pellets (10 mm diameter and ~ 1 mm thickness) sintered at 800, 1000, 1200, and 1500 °C. Electrodes were made by coating opposite faces of the pellets with SPI-ChemTM conductive Pt paint and firing them at 800 °C to eliminate organic components and harden the Pt residue. Data were recorded for each sample from 250 to 600 °C over the 100 Hz–1 MHz frequency range. All measurements were made under N_2 gas flow to ensure an inert atmosphere. Measurements were also done under air flow and no difference was observed.

Raman spectra were recorded with a Bruker FT-Raman RFS 100/S spectrometer. Excitation was performed with a Nd^{3+} -doped yttrium aluminum garnet laser and the spectral

resolution was 2 cm^{-1} . Differential thermal analysis was performed in air in a Perkin-Elmer TAC/DX analyzer using a typical sample size of 10 mg and a heating rate of 10 °C/min.

III. RESULTS AND DISCUSSION

A. Structural characterization

1. XRD

Figure 1 shows the x-ray-diffraction (XRD) patterns of the $\text{Gd}_2(\text{Ti}_{0.65}\text{Zr}_{0.35})_2\text{O}_7$ samples obtained by ball milling and subjected to a 12 h thermal treatment at 800, 1000, and 1200 °C. Results obtained from the structural refinements are collected in Table I together with their microstructural features obtained from the corresponding Langford plots.^{17,18} As the pyrochlore structure can be considered as a superstructure of an anion-deficient fluorite like atomic arrangement, its diffraction pattern contains a set of strong peaks characteristic of the fluorite-type substructure plus an additional set of superstructure reflections. The intensities of the latter depend on factors such as the degree of ordering, difference in the average scattering factors of the elements involved, distribution of oxygen vacancies, etc.⁸ Since no superstructure peaks due to the pyrochlore long-range atomic ordering are evident in Fig. 1(a), we might conclude that the as-prepared $\text{Gd}_2(\text{Ti}_{0.65}\text{Zr}_{0.35})_2\text{O}_7$ powders present an anion-deficient fluorite type of structure which remains stable, at least, up to a temperature of 800 °C. No additional phases are apparently present. As Figs. 1(b) and 1(c) show, powders treated at higher temperatures present XRD patterns containing all the characteristic reflections of pyrochlore-like materials [note the (331) peak in the inset of both figures]. As the structure factors (F_{hkl}) of the superstructure peaks depend on the difference of scattering power between the 16c and the 16d sites and those of peaks with h , k , and l even depend on the addition of the scattering power in both positions (constant along the whole series as the composition is), the relative intensity of the superstructure peaks is a direct evidence of the cation distribution in the structure. Therefore, judging from the relative intensity of their superstructure peaks, samples fired at 1000 and 1200 °C show different cation distributions. As mentioned before and based merely on metal ion size, one would expect the 16c site in pyrochlores to be fully occupied by the larger Gd^{3+} ions, whereas the smaller Ti^{4+} and Zr^{4+} ions would share the hexacoordinated position (16d) [$r(\text{Ti}^{4+})=0.61 \text{ \AA}$], $r(\text{Zr}^{4+})=0.72 \text{ \AA}$, and $r(\text{Gd}^{3+})=0.94 \text{ \AA}$, all in octahedral coordination].¹⁹ Therefore, as a starting model for our refinements, we assumed all the Gd ions to be constrained into the 16c site and correspondingly, the existing Ti and Zr ions sharing the 16d position, but it became evident during the process that much more scattering power should be located in the 16d site which could only be accomplished by allowing Gd ions to move into the latter and consequently, removing either Ti or Zr. From crystallochemical considerations, the obvious choice was Zr and we refined the occupation of both sites allowing Zr to move to the 16c site and Gd to occupy the 16d position. The final refined distribution presented in Table

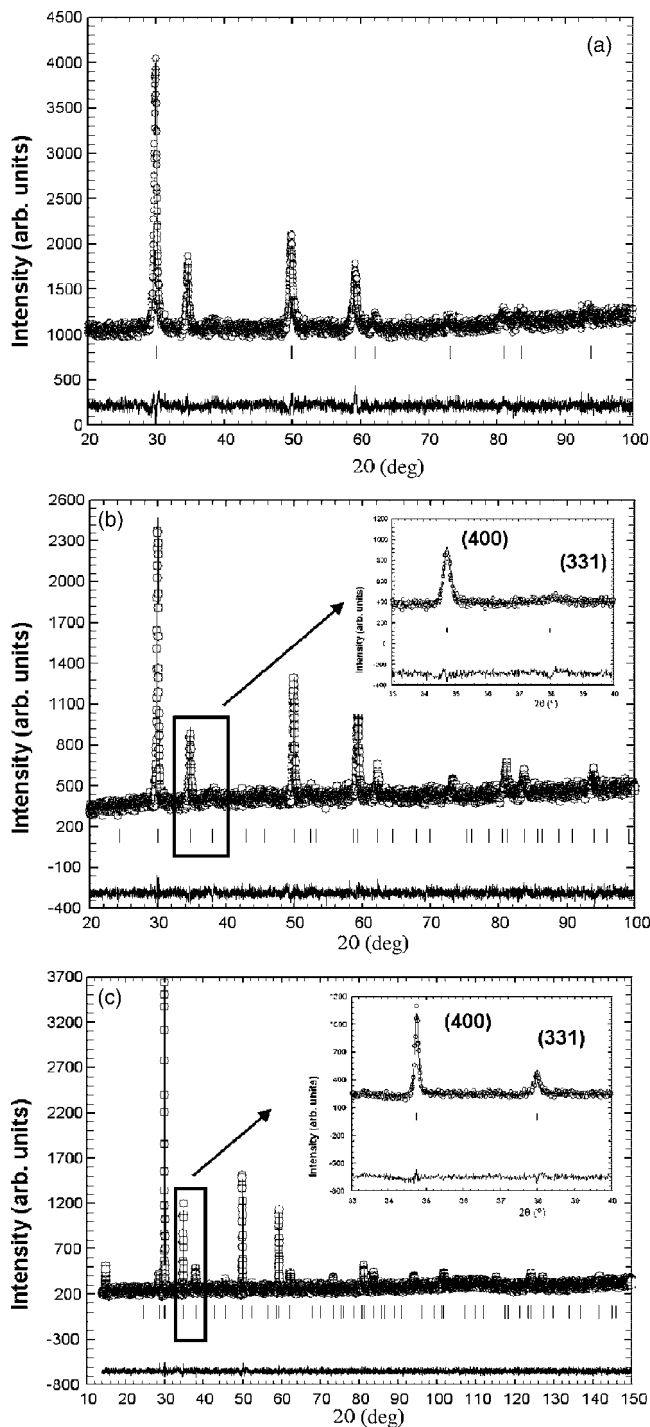


FIG. 1. Experimental (points), calculated (solid line), and difference (bottom) x-ray-diffraction patterns for as-prepared $\text{Gd}_2(\text{Ti}_{0.65}\text{Zr}_{0.35})_2\text{O}_7$ powder sample fired at (a) 800, (b) 1000, and (c) 1200 °C. In the inset of (b) and (c), a zone of the pattern is magnified to show the relative intensity of the (331) pyrochlore superstructure peak.

I shows an important fraction of Gd ions to be located at the hexacoordinated $16d$ site, even after firing the powder samples at very high temperatures (above 10% at 1500 °C) and driving as a consequence a significant fraction of Zr^{4+} ions to the $16c$ sites (above 30% at 1500 °C). Therefore,

although the structural refinement suggests a progressive ordering as the temperature of the postmilling thermal treatment increases, even the sample fired at 1500 °C presents a partially disordered cation sublattice as a result of the chemically (Zr substitution) and mechanically induced disordering. Regarding the microstructural features of these samples, data collected in Table I show that mechanochemically induced defects are difficult to relax and temperatures higher than 1200 °C are needed for the strain to decrease significantly, remaining essentially the same for the just-milled sample and for those fired at temperatures of up to 1000 °C. On the contrary, the domain size varies gradually with the firing temperature (almost like an exponential growth as observed for many temperature-activated processes). As x-ray-diffraction techniques are not adequate to study structural features related to light atoms such as oxygen, the oxygen array in our structural refinements is assumed to be ordered as in the ideal pyrochlore structure, whereas in fluorite, 1/8 of the oxygen positions are empty at random.

2. Raman spectroscopy

We have performed Raman spectroscopy measurements for the study of oxygen disorder, as described previously on pyrochlores and fluorites.^{10,20,21} Raman spectroscopy is especially suited for analyzing anion disorder in $A_2B_2\text{O}(1)_6\text{O}(2)$ pyrochlore oxides since their spectra are entirely produced by the vibrations of the anion substructure, whereas the A and B cations, whose site symmetry is D_{3d} , give rise to non-active Raman phonon modes. Vibrations of the oxygen atoms located at the $48f$ positions with C_{2v} site symmetry, O(1), contribute to five phonon modes ($A_{1g} + E_g + 3T_{2g}$), whereas those bonded to the A cation, the O(2), give a single T_{2g} mode. As for fluorites, there is only one vibrational mode Raman active (T_{2g}); with the form of the anions vibrating against the symmetry-fixed cations, it is very easy to distinguish between both structural arrangements. On the other hand, it has been shown that the increasing occupancy of the initially vacant $8b$ site in the pyrochlore structure gives rise to the development of a new and broad vibrational Raman band near 750 cm^{-1} which has been assigned to seven-coordinated Ti atoms.²¹

Raman spectra collected for our just-milled sample and those milled and thermally treated at 800, 1000, and 1200 °C are presented in Fig. 2. Spectra obtained for the just-milled sample and that fired at 800 °C show the presence of very broad bands near 340 and 750 cm^{-1} and are similar to that presented by Hess *et al.* for pure defect fluorite-type $\text{Gd}_2\text{Zr}_2\text{O}_7$ prepared by sintering of oxides.²⁰ However, firing above that temperature produces significant changes in the Raman spectra; i.e., new bands develop at 712 , 520 , and 436 cm^{-1} which undoubtedly point to the formation of a pyrochlore type of structure and are a clear indication of a phase transition on heating the as-prepared metastable $\text{Gd}_2(\text{Ti}_{0.65}\text{Zr}_{0.35})_2\text{O}_7$ powders above 800 °C. Interestingly enough, the band near 750 cm^{-1} remains present even after firing the sample at 1200 °C although much weaker and narrower, suggesting the presence of residual oxygen disordering even at this temperature. As shown by XRD, it is also clear here that there are some differences between samples

TABLE I. Structural evolution of metastable $Gd_2(Ti_{0.65}Zr_{0.35})_2O_7$ powders prepared by mechanical milling.

Treatment T (°C)/time (h)	800/12	1000/12	1200/12	1500/12	
Structural type	Fluorite		Pyrochlore		
Symmetry	$Fm\bar{3}m$ (n. 225)		$Fd\bar{3}m$ (n. 227)		
a (Å)	5.1698(7)	a (Å)	10.3208(2)	10.3171(1)	10.3171(1)
Gd/Ti/Zr in $4a$, $m\bar{3}m$, (0 0 0), Occ.	0.5/0.65/0.35	Gd/Zr/Ti in $16c$, $\bar{3}m$, (0 0 0), Occ.	0.57(2)/0.35/0.08(2)	0.80(2)/0.20(2)/0.0	0.87(1)/0.13(1)/0.0
O(1) in $8c$, $\bar{4}3m$ ($\frac{1}{4} \frac{1}{4} \frac{1}{4}$), Occ.	7/8	Gd/Zr/Ti in $16d$, $\bar{3}m$, ($\frac{1}{2} \frac{1}{2} \frac{1}{2}$), Occ.	0.43(2)/0.0/0.57(2)	0.20(2)/0.15(2)/0.65	0.13(1)/0.22(1)/0.65
		O(1) in $48f$, mm ($\times 1/8 1/8$), Occ.	1		
		x	0.415(2)	0.417(1)	0.416(1)
		O(2) in $8a$, $\bar{4}3m$, ($1/8 1/8 1/8$), Occ.	1		
R_B	0.048		0.054	0.055	0.053
R_{wp}	0.034		0.050	0.062	0.044
R_{exp}	0.029		0.047	0.059	0.042
χ^2	1.33		1.12	1.13	1.09
$\langle D_{iso} \rangle$ (Å) ^a	150(20)		145(4)	284(20)	3800(300)
e_{rms} ^b	$5(1) \times 10^{-3}$		$3(2) \times 10^{-3}$	$1(1) \times 10^{-4}$	$1(1) \times 10^{-4}$

^aAverage domain diameter assuming spherical shape.

^bRoot-mean-square strain.

fired at 1000 and 1200 °C; i.e., the Raman spectrum of the latter shows higher intensity of the 520 cm^{-1} band, lower intensity of the band near 750 cm^{-1} , and smaller bandwidth of the 430 cm^{-1} band when compared with the sample fired

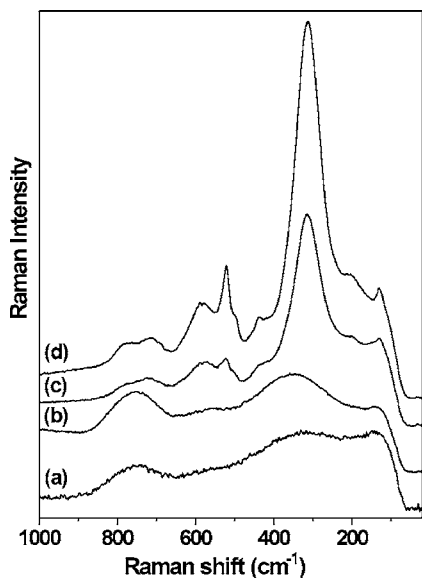


FIG. 2. Raman spectra obtained for the $Gd_2(Ti_{0.65}Zr_{0.35})_2O_7$ samples (a) just milled and for the same sample but subjected to postmilling thermal treatments at (b) 800 °C, (c) 1000 °C, and (d) 1200 °C.

at 1000 °C. These changes indicate that the ordering process is continuous, involving not only the metal substructure but also the anion sublattice.

The presence in the differential thermal analysis curve of an exothermic event confirms the existence of a phase transition on heating the as-prepared $Gd_2(Ti_{0.65}Zr_{0.35})_2O_7$ powders at temperatures close to 860 °C (see Fig. 3). This event was also observed on disordered $A_2Ti_2O_7$ pyrochlores (A

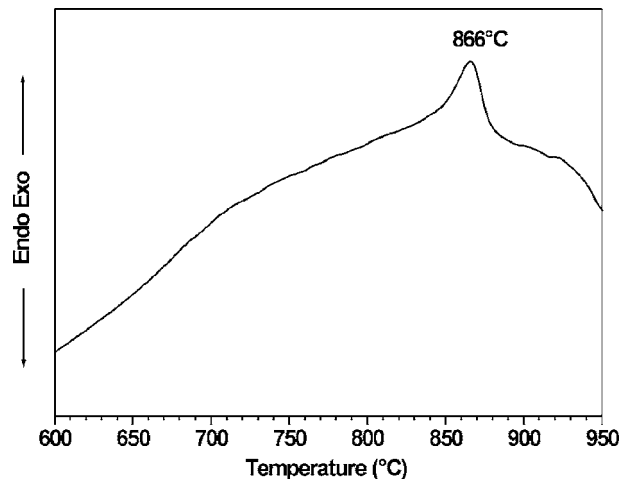


FIG. 3. Differential analysis curve obtained for the as-prepared $Gd_2(Ti_{0.65}Zr_{0.35})_2O_7$ powders showing the presence of an exothermic event assigned to an anion-deficient fluorite to pyrochlore phase transition.

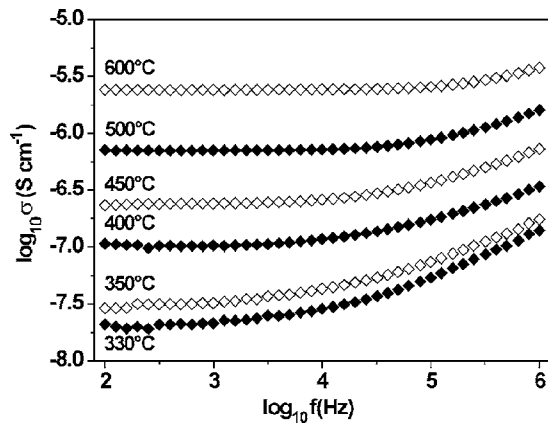


FIG. 4. Frequency dependence of the real part of the electrical conductivity $\sigma'(\omega)$ at different temperatures for the as-prepared $\text{Gd}_2(\text{Ti}_{0.65}\text{Zr}_{0.35})_2\text{O}_7$ powders sintered at 1500°C .

=Gd, Y, Dy) prepared by mechanical milling and was associated mainly with an oxygen rearrangement process since it was present in $\text{Y}_2\text{Ti}_2\text{O}_7$ and $\text{Dy}_2\text{Ti}_2\text{O}_7$, showing cation and anion partially disordered substructures, as well as in $\text{Gd}_2\text{Ti}_2\text{O}_7$, where disorder was constrained to the anion substructure.¹⁰ This disorder-order transition seems to be first order as evidenced by strong heat effects.

Hence, mechanochemically prepared $\text{Gd}_2(\text{Ti}_{0.65}\text{Zr}_{0.35})_2\text{O}_7$ powders present an anion-deficient fluorite type of structure at room temperature and postmilling thermal treatments at temperatures higher than $\sim 860^\circ\text{C}$ facilitate long-range atomic ordering characteristic of pyrochlores. However, cation and anion orderings evolve at different rates. That is, while the anion substructure orders mostly in a narrow temperature range around 860°C , the ordering of the cation substructure is sluggish, and very high temperatures (1500°C) are needed to complete the process. This is most likely related to the well-known extremely slow rate of cation diffusion in fluorite-related stabilized zirconia based materials.

B. Electrical conductivity relaxation

In order to study the influence of the increasingly ordered structure found when increasing sintering temperature on oxygen dynamics, we performed electrical conductivity relaxation measurements. Figure 4 shows the frequency dependence of the real part of the electrical conductivity $\sigma'(\omega)$ at different temperatures for the as-prepared $\text{Gd}_2(\text{Ti}_{0.65}\text{Zr}_{0.35})_2\text{O}_7$ powders sintered at 1500°C , selected as representative of the series; similar plots were obtained for all the samples sintered at different temperatures and analyzed in this work. It can be observed that at high frequencies and/or low temperatures, isothermal conductivity data curves show a Jonscher-type²² power-law dependence of the form $\sigma'(\omega) \propto \omega^n$ with a fractional exponent n . Increasing temperature and/or decreasing frequency leads to a regime with a frequency-independent conductivity value σ_{dc} , which is the bulk dc conductivity. Thus, σ_{dc} at a given temperature can be directly obtained from ac conductivity measurements

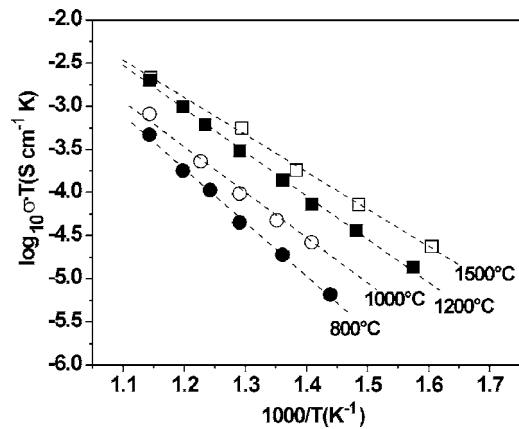


FIG. 5. Arrhenius plots showing the temperature dependence of the dc conductivity obtained for various samples sintered at different temperatures between 800 and 1500°C .

as the conductivity value in the “plateau” region of the isothermal curves in Fig. 4. We want to remark that conductivity values were not affected by measuring under N_2 or air flows, and the electronic contribution to the conductivity, if any, was negligible, as determined by dc conductivity measurements using the same Pt electrodes. Figure 5 is an Arrhenius plot showing the temperature dependence of the ionic dc conductivity due to mobile oxygen ions for various samples sintered at different temperatures. All samples show a thermally activated behavior, $\sigma_{dc} = (\sigma_\infty/T) \exp(-E_{dc}/kT)$, and the activation energy, E_{dc} , for the dc conductivity is found to decrease from 1.23 ± 0.04 to 0.78 ± 0.03 eV as the sintering temperature increases from 800 to 1500°C .

The power-law frequency dependence observed in the ac conductivity in Fig. 4 has been previously related to the existence of cooperative effects in the dynamics of hopping ions, with the fractional exponent n ($0 \leq n < 1$) determined by the degree of ion-ion interactions existing in the ionic hopping process; i.e., in the absence of interactions among mobile ions (independent random ion hopping), the exponent n would be 0, while n would tend to 1 for a completely correlated ion motion.^{23,24} An alternative representation of experimental conductivity data can be made by plotting the frequency dependence of the complex electric modulus, $M^*(\omega)$, which is directly related to the complex conductivity as $M^*(\omega) = 1/\varepsilon^*(\omega) = j\omega\varepsilon_0/\sigma^*(\omega)$, with ε_0 the permittivity of vacuum. The use of the electric modulus allows us to obtain the relaxation function $\Phi(t)$ in the time domain for the decay of the electric field inside the material under the constraint of a constant displacement vector.^{25,26} Under a constant displacement vector between the electrodes, ions will diffuse inside the material until a concentration gradient is created which cancels the electric field. Thus, the decay of the electric field [and its exact time dependence $\Phi(t)$] is related to how ions can diffuse inside the material between the electrodes. It is found that the frequency dependence of the electric modulus is given directly by the Laplace transform of the time derivative of the relaxation function

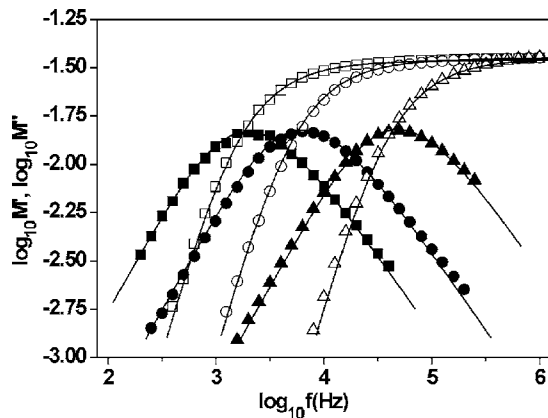


FIG. 6. Frequency dependence of the real (open symbols) and imaginary (solid symbols) parts of the electric modulus for the as-prepared $\text{Gd}_2(\text{Ti}_{0.65}\text{Zr}_{0.35})_2\text{O}_7$ powders sintered at $1500\text{ }^\circ\text{C}$ at selected temperatures (from left to right, 350 , 400 , and $500\text{ }^\circ\text{C}$). Solid lines are best fits according to a KWW relaxation function.

$$M^*(\omega) = \frac{1}{\epsilon_\infty} \left[1 - \int_0^\infty \left(-\frac{d\Phi}{dt} \right) e^{-j\omega t} dt \right], \quad (1)$$

where ϵ_∞ is the permittivity value at high frequencies, and therefore the spectral shape and characteristic time of the electric modulus are determined by the dynamics of mobile ions which we are interested in. The relaxation function $\Phi(t)$ in ionic conductors is usually found to be nonexponential and can be well described by Kohlrausch-Williams-Watts (KWW) functions^{26,27} of the form

$$\Phi(t) = \exp[-(t/\tau)^{1-n}], \quad 0 < (1-n) \leq 1. \quad (2)$$

The relaxation time τ is a characteristic time for the ion hopping process and it is therefore thermally activated with the same activation energy of the dc conductivity. The exponent n in the KWW function gives rise to the power-law frequency dependence of the ac conductivity at the highest frequencies and is a measure of the departure from the pure exponential or Debye behavior expected for uncorrelated ion hopping.

Figure 6 shows the frequency dependence of the real and imaginary parts of the electric modulus for the same sample shown in Fig. 4, as-prepared $\text{Gd}_2(\text{Ti}_{0.65}\text{Zr}_{0.35})_2\text{O}_7$ powders sintered at $1500\text{ }^\circ\text{C}$, but only at three selected temperatures for clarity. An asymmetric peak is observed in the imaginary part $M''(\omega)$, with the maximum at a characteristic frequency $\omega_p \approx \tau^{-1}$ increasing with temperature. Solid lines in the figure are best fits to KWW functions, from which the exponent n can be determined. The shape of the electric modulus, and thus the value of the exponent n , was found to be temperature independent within experimental error. The excellent agreement between the KWW fits and the experimental data can be observed. Interestingly, the value of the parameter n was found to change significantly from sample to sample when sintered at different temperatures. The inset of Fig. 7 shows how the exponent n decreases systematically from 0.51 ± 0.01 to 0.18 ± 0.01 when the sintering temperature increases from 800 to $1500\text{ }^\circ\text{C}$. The main panel in the same

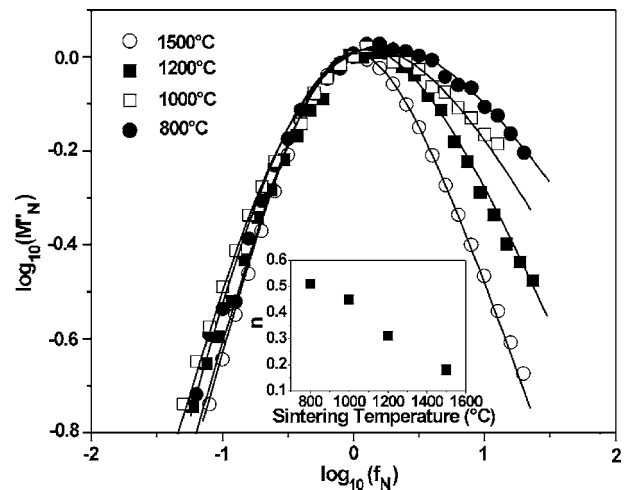


FIG. 7. Frequency dependence of the imaginary part of the electric modulus for as-prepared $\text{Gd}_2(\text{Ti}_{0.65}\text{Zr}_{0.35})_2\text{O}_7$ powders sintered at different temperatures. Note that experimental data have been horizontally and vertically shifted by normalizing to the corresponding peak frequency and peak height values in each curve. Solid lines are fits according to a KWW relaxation function, and the inset shows the systematic and significant decrease in the value of the exponent n in the KWW fit as the sintering temperature increases.

figure shows the frequency dependence of the imaginary part of the electric modulus for as-prepared powders sintered at the different temperatures, showing how the peak narrows with increasing sintering temperature. Peak narrowing corresponds to lower n values in the KWW fit to electric modulus spectra.

It has been recently proposed that the different degrees of porosity (density) in ceramic samples might play a role in determining the values of the exponent n .²⁸ However, since density values range from 80% to 95% in our samples, only a small effect would be expected in the exponent n as a consequence of microstructural differences, and a major role seems to be played, as discussed below, by changes in the degree of ion-ion correlations triggered by structural disorder. Interestingly, our results of the concomitant decrease of the activation energy E_{dc} for the dc conductivity (see Fig. 5) and of the n value (see inset of Fig. 7), as the sintering temperature is increased, can be rationalized in terms of the coupling model (CM).^{24,29,30} The CM starts with the consideration of the independent hops of ions to vacant adjacent sites with exponential correlation function, $\Phi(t) = \exp(-t/\tau_0)$, and relaxation time τ_0 . Such independent hops cannot occur for all ions at the same time because of ion-ion interactions and correlations. The result of ion-ion interactions is the slowing down of the relaxation rate at times longer than t_c of the order of 2 ps , changing the correlation function from a pure exponential to a KWW function, $\Phi(t) = \exp[-(t/\tau)^{1-n}]$, wherein the value of the fractional exponent n is a measure of the cooperative effects. A major result from the CM is that the effective relaxation time τ is related to τ_0 by

$$\tau = [t_c^{-n} \tau_0]^{1/(1-n)}. \quad (3)$$

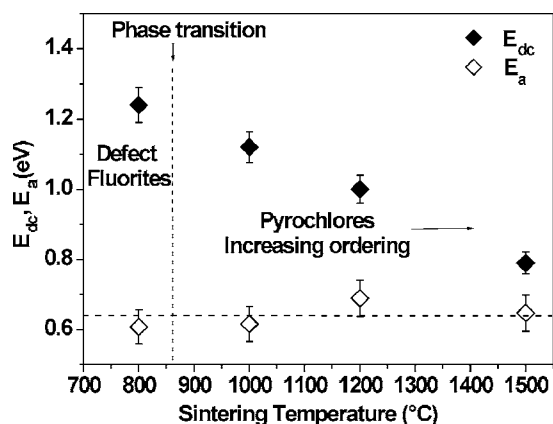


FIG. 8. Values obtained for the activation energy of the dc conductivity E_{dc} and the energy barrier $E_a=(1-n)E_{dc}$ as a function of the sintering temperature. The horizontal dashed line represents the average E_a value, whereas the vertical line represents the temperature of the phase transition observed when firing mechanochemically prepared $Gd_2(Ti_{0.65}Zr_{0.35})_2O_7$ powders from a disordered fluorite to an increasingly ordered pyrochlore structure.

For ions vibrating in their cages and hopping to neighboring sites through barriers of energy E_a , the relaxation time for independent ion hopping is $\tau_0(T)=\tau_\infty \exp(E_a/kT)$. The reciprocal of τ_∞ is the attempt frequency of ions. It follows from Eq. (3) that the activation energy for the dc conductivity or τ will be larger than the energy barrier and is given by the relation

$$E_{dc} = E_a/(1 - n). \quad (4)$$

The increase of ion-ion interaction leads to a higher degree of cooperativity in the ion hopping process which corresponds to a higher value of n and, consequently, to higher activation energy E_{dc} for long-range ionic transport, due to the energy penalty that ion-ion interactions impose on the ionic diffusion process.

In fact, when we estimate the activation energy E_a for the barrier that oxygen ions must overcome to hop (independently) between neighboring $48f$ sites, according to Eq. (4) and by using the experimental values obtained for E_{dc} and n , we find in all samples a value of $E_a=0.64\pm 0.05$ eV that remains independent of the sintering temperature within experimental error. Figure 8 shows the values obtained for the energy barrier $E_a=(1-n)E_{dc}$ as a function of the sintering temperature, together with the values obtained for E_{dc} from the Arrhenius fits in Fig. 5. As deduced from the structural

characterization, a lower sintering temperature leads to a more disordered structure. The probability and direction of the hopping events performed by the mobile oxygen ions depend on their local potential landscape, which in a disordered structure will be determined by the distribution of other mobile ions in the neighboring oxygen sites. The hopping probability of a particular mobile ion will be strongly dependent on the position of the neighboring mobile ions (and therefore on the previous hopping events). Thus, ion dynamics becomes more correlated in a disordered structure, and consequently higher values of the exponent n are expected according to the CM. The same argument explains the observed increase in the dc activation energy E_{dc} when lowering the sintering temperature. A more disordered structure of the oxygen sublattice in samples sintered at lower temperatures (as described by the Raman spectra) fosters ion-ion correlations, and stronger correlations lead to an increase of the energy penalty imposed to the long-range or dc ionic conductivity, as observed for the dc activation energy E_{dc} . This explains the fact that the lower the sintering temperature, the larger the difference found between E_{dc} and E_a (higher value of n) as seen in Fig. 8.

IV. CONCLUSIONS

We have shown in this work the feasibility of preparing metastable anion-deficient fluorite-type $Gd_2(Ti_{0.65}Zr_{0.35})_2O_7$ powders by mechanical milling starting from constituent oxides. Postmilling thermal treatments allow some ordering to take place though both cation and anion substructures order at different rates: the first orders gradually with temperature, whereas the latter orders mostly around 860 °C. Interestingly enough, transient pyrochlores with a very unusual cation distribution are obtained above 800 °C. We have found that the activation energy for the dc conductivity decreases with increasing sintering temperature, thus leading to higher ionic conductivity values. From the analysis of electrical conductivity relaxation, we also found that there is a coupled decrease of the exponent n in the KWW functions characterizing the dynamics of oxygen ions. This behavior is explained as due to the enhancement of ion-ion interactions promoted by the more disordered structure in samples sintered at lower temperatures.

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